



# μ **ΡΑ1560**

### N-CHANNEL POWER MOS FET ARRAY SWITCHING INDUSTRIAL USE

#### DESCRIPTION

The  $\mu$ PA1560 is N-Channel Power MOS FET Array that built in 4 circuits designed for solenoid, motor and lamp driver.

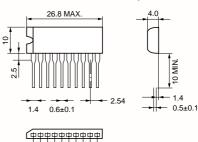
#### **FEATURES**

- Full mold package with 4 circuits
- 4 V driving is possible
- Low on-state resistance  $R_{DS(on)1} = 165 \text{ m}\Omega \text{ MAX.}$  (VGs = 10 V, ID = 1.5 A)  $R_{DS(on)2} = 200 \text{ m}\Omega \text{ MAX.}$  (VGs = 4 V, ID = 1.5 A)
- Low input capacitance C<sub>iss</sub> = 600 pF TYP.

#### **ORDERING INFORMATION**

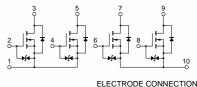
PART NUMBER	PACKAGE
$\mu$ PA1560H	10-pin SIP

#### PACKAGE DRAWING (Unit : mm)



1 2 3 4 5 6 7 8 910

#### EQUIVALENT CIRCUIT



ELECTRODE CONNECTION 2, 4, 6, 8 : Gate 3, 5, 7, 9 : Drain 1, 10 : Source

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	120	V
Gate to Source Voltage (VDS = 0 V)	VGSS(AC)	±20	V
Gate to Source Voltage (VDS = 0 V)	VGSS(DC)	+ 20, -10	V
Drain Current (DC)	D(DC)	±3.0	А
Drain Current (pulse) Note1	D(pulse)	±12	А
Total Power Dissipation (Tc = 25°C)	<b>P</b> T1	28	W
Total Power Dissipation (T <sub>A</sub> = 25°C)	<b>P</b> T2	3.7	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to + 150	°C
Single Avalanche Current Note2	las	3.0	А
Single Avalanche Energy Note2	Eas	0.9	mJ

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %

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2. Starting T_{ch} = 25 \text{ °C}, V_{DD} = 60 \text{ V}, R_G = 25 \Omega, V_{GS} = 20 \text{ V} \rightarrow 0 \text{ V}
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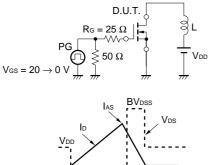
**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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#### ELECTRICAL CHARACTERISTICS (TA = 25 °C)

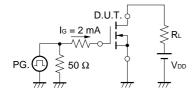
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 1.5 A		130	165	mΩ
	RDS(on)2	Vgs = 4.0 V, Id = 1.5 A		145	200	mΩ
Gate to Source Cut-off Voltage	VGS(off)	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1.0 \text{ mA}$	1.0	1.8	2.5	V
Forward Transfer Admittance	y₁s	Vds = 10 V, Id = 1.5 A	2	4.5		S
Drain Leakage Current	IDSS	V <sub>DS</sub> = 120 V, V <sub>GS</sub> = 0 V			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		600		pF
Output Capacitance	Coss	V <sub>G</sub> s = 0 V		160		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		70		pF
Turn-on Delay Time	td(on)	ID = 1.5 A		35		ns
Rise Time	tr	$V_{GS(on)} = 10 V$		80		ns
Turn-off Delay Time	td(off)	Vdd = 60 V		700		ns
Fall Time	tr	RL = 30 Ω		250		ns
Total Gate Charge	QG	ID = 3.0 A		28		nC
Gate to Source Charge	QGS	Vdd = 96 V		2.5		nC
Gate to Drain Charge	Qgd	Vgs = 10 V		9		nC
Body Diode Forward Voltage	VF(S-D)	IF = 3.0 A, VGS = 0 V		0.9		V
Reverse Recovery Time	trr	IF = 3.0 A, VGS = 0 V		160		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/ μs		280		nC

#### **TEST CIRCUIT 1 AVALANCHE CAPABILITY**

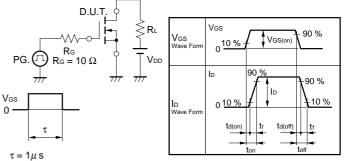


- Starting Tch

#### **TEST CIRCUIT 3 GATE CHARGE**



#### **TEST CIRCUIT 2 SWITCHING TIME**



 $\tau = 1\mu s$ Duty Cycle  $\leq 1 \%$ 

## NEC

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